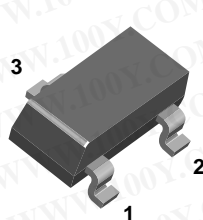
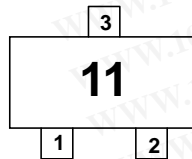


MMBD1501/A / 1503/A / 1504/A / 1505/A



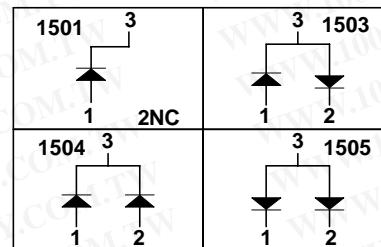
SOT-23



MARKING

MMBD1501	11	MMBD1501A	A11
MMBD1503	13	MMBD1503A	A13
MMBD1504	14	MMBD1504A	A14
MMBD1505	15	MMBD1505A	A15

Connection Diagrams



Small Signal Diodes

Absolute Maximum Ratings*

$T_A = 25^\circ\text{C}$ unless otherwise noted

Symbol	Parameter	Value	Units
V_{RRM}	Maximum Repetitive Reverse Voltage	200	V
$I_{F(AV)}$	Average Rectified Forward Current	200	mA
I_{FSM}	Non-repetitive Peak Forward Surge Current Pulse Width = 1.0 second Pulse Width = 1.0 microsecond	1.0 2.0	A A
T_{stg}	Storage Temperature Range	-55 to +150	$^\circ\text{C}$
T_J	Operating Junction Temperature	150	$^\circ\text{C}$

*These ratings are limiting values above which the serviceability of any semiconductor device may be impaired.

NOTES:

- 1) These ratings are based on a maximum junction temperature of 150 degrees C.
- 2) These are steady state limits. The factory should be consulted on applications involving pulsed or low duty cycle operations

Thermal Characteristics

Symbol	Parameter	Value	Units
P_D	Power Dissipation	350	mW
$R_{\theta JA}$	Thermal Resistance, Junction to Ambient	357	$^\circ\text{C/W}$

Electrical Characteristics

$T_A = 25^\circ\text{C}$ unless otherwise noted

Symbol	Parameter	Test Conditions	Min	Max	Units
V_R	Breakdown Voltage	$I_R = 5.0 \mu\text{A}$	200		V
V_F	Forward Voltage	$I_F = 1.0 \text{ mA}$ $I_F = 10 \text{ mA}$ $I_F = 50 \text{ mA}$ $I_F = 100 \text{ mA}$ $I_F = 200 \text{ mA}$ $I_F = 300 \text{ mA}$	620 720 800 830 0.87 0.90	720 830 890 930 1.1 1.15	mV mV mV mV V V
I_R	Reverse Current	$V_R = 125 \text{ V}$ $V_R = 125 \text{ V}, T_A = 150^\circ\text{C}$ $V_R = 180 \text{ V}$ $V_R = 180 \text{ V}, T_A = 150^\circ\text{C}$		1.0 3.0 10 5.0	nA μA nA μA
C_T	Total Capacitance	$V_R = 0, f = 1.0 \text{ MHz}$		4.0	PF

Small Signal Diode (continued)

Typical Characteristics

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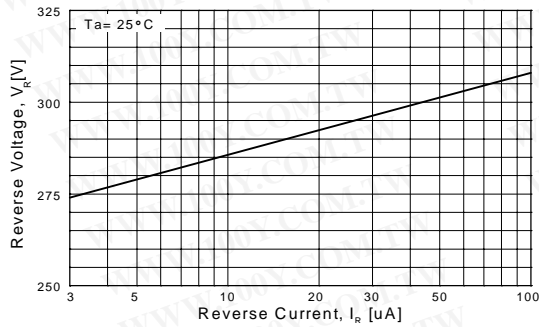


Figure 1. Reverse Voltage vs Reverse Current
BV - 3.0 to 100 uA

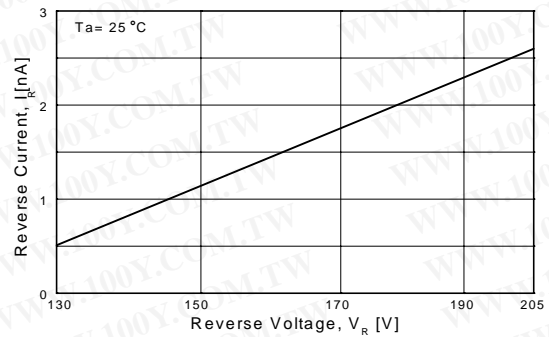


Figure 2. Reverse Current vs Reverse Voltage
IR - 130 - 250 Volts

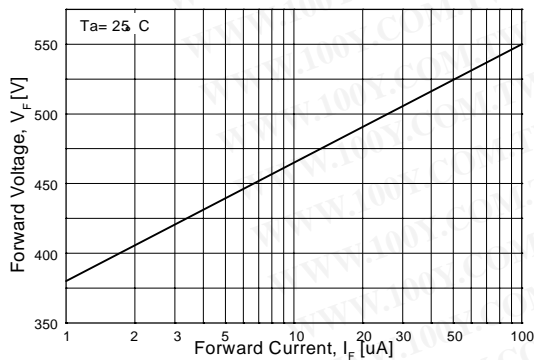


Figure 3. Forward Voltage vs Forward Current
VF - 1 to 100 uA

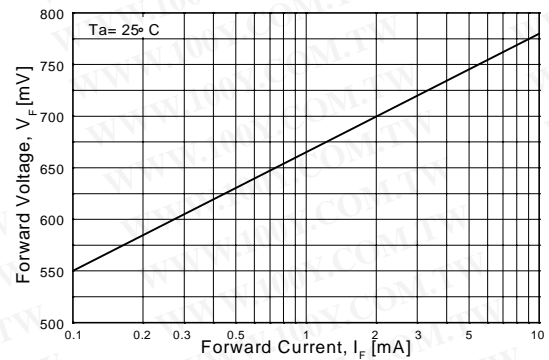


Figure 4. Forward Voltage vs Forward Current
VF - 0.1 to 10 mA

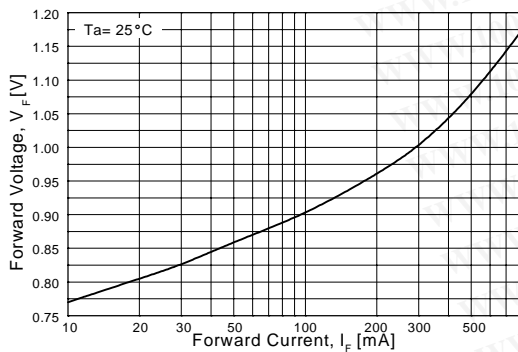


Figure 5. Forward Voltage vs Forward Current
VF - 10 to 800 mA

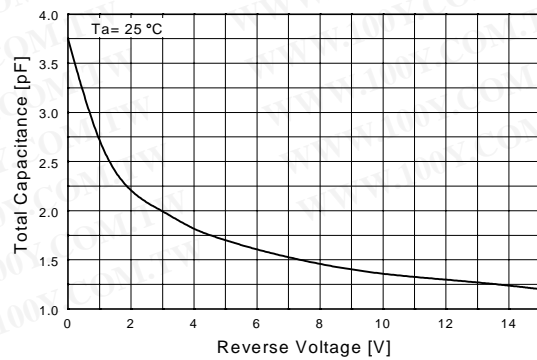


Figure 6. Total Capacitance vs Reverse Voltage
VR - 0 to 15 V

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Typical Characteristics (continued)

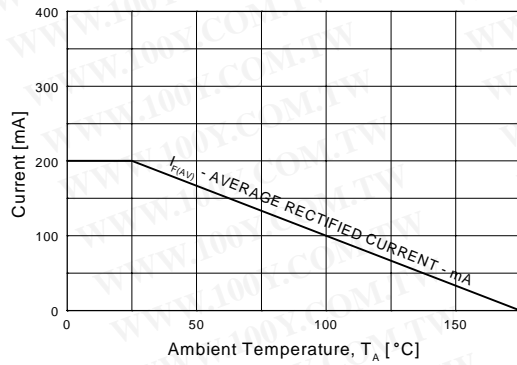


Figure 7. Average Rectified Current ($I_{F(AV)}$) versus Ambient Temperature (T_A)

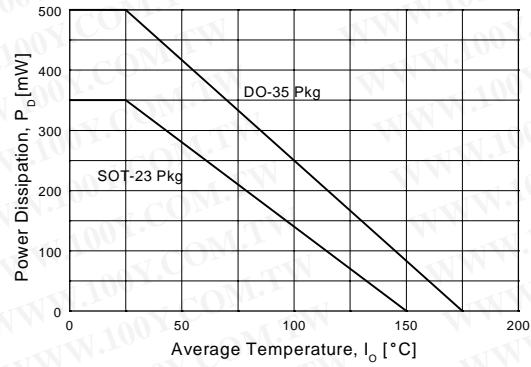


Figure 8. Power Derating Curve

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